National Semiconductor

CD4029BM/CD4029BC Presettable Binary/Decade Up/Down Counter

General Description

The CD4029BM/CD4029BC is a presettable up/down counter which counts in either binary or decade mode depending on the voltage level applied at binary/decade input. When binary/decade is at logical "1," the counter counts in binary, otherwise it counts in decade. Similarly, the counter counts up when the up/down input is at logical "1" and vice versa.

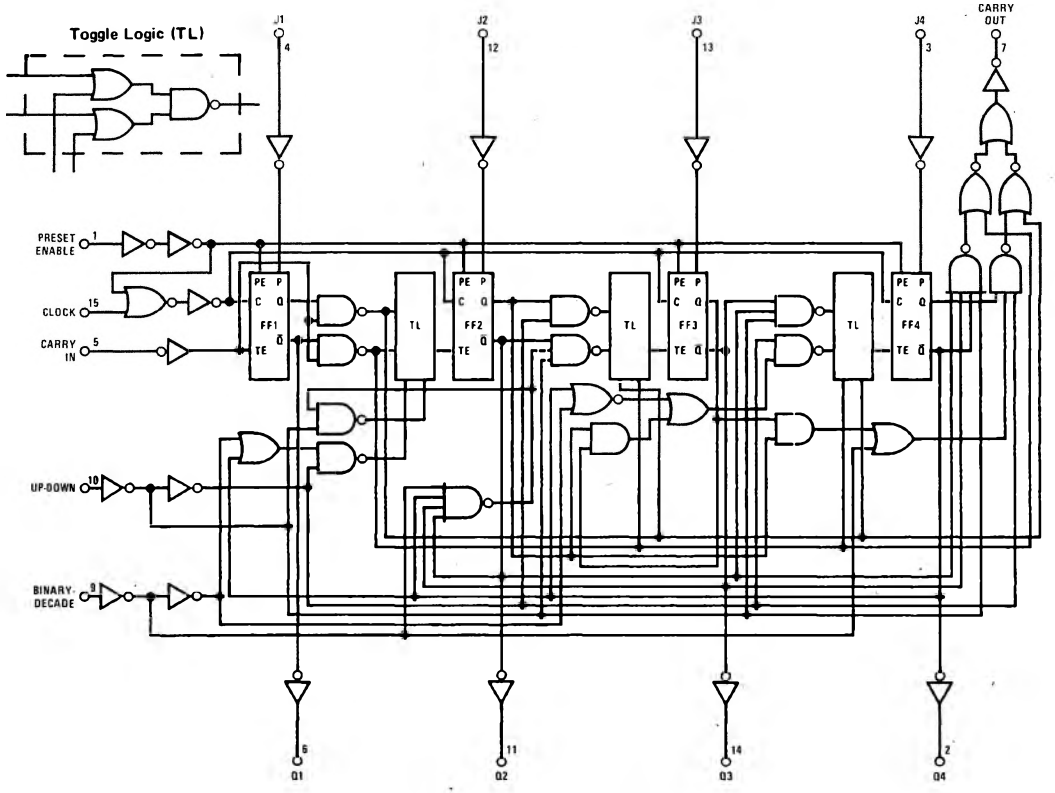
A logical "1" preset enable signal allows information at the "jam" inputs to preset the counter to any state asynchronously with the clock. The counter is advanced one count at the positive-going edge of the clock if the carry in and preset enable inputs are at logical "0." Advancement is inhibited when either or both of these two inputs is at logical "1." The carry out signal is normally at logical "1" state and goes to logical "0" state when the counter reaches its maximum count in the "up" mode or the minimum count in the "down" mode provided the carry input is at logical "0" state.

All inputs are protected against static discharge by diode clamps to both V_{DD} and V_{SS}.

Features

- Wide supply voltage range — 3V to 15V
- High noise immunity — 0.45 V_{DD} (typ.)
- Low power TTL compatibility — fan out of 2 driving 74L or 1 driving 74LS
- Parallel jam inputs
- Binary or BCD decade up/down counting

Logic Diagram



Absolute Maximum Ratings

(Notes 1 and 2)

V_{DD} dc Supply Voltage	−0.5 to +18 V_{DC}
V_{IN} Input Voltage	−0.5 to V_{DD} + 0.5 V_{DC}
T_S Storage Temperature Range	−65°C to +150°C
P_D Package Dissipation	500 mW
T_L Lead Temperature (Soldering, 10 seconds)	300°C

Recommended Operating Conditions

(Note 2)

V_{DD} dc Supply Voltage	3 to 15 V_{DC}
V_{IN} Input Voltage	0 to V_{DD} V_{DC}
T_A Operating Temperature Range	
CD4029BM	−55°C to +125°C
CD4029BC	−40°C to +85°C

DC Electrical Characteristics CD4029BM (Note 2)

PARAMETER		CONDITIONS	−55°C		25°C			125°C		UNITS
			MIN	MAX	MIN	TYP	MAX	MIN	MAX	
I_{DD}	Quiescent Device Current	V_{DD} = 5V		5			5	5	150	μA
		V_{DD} = 10V		10			10		300	μA
		V_{DD} = 15V		20			20		600	μA
V_{OL}	Low Level Output Voltage	$\|I_O\| < 1\mu A$								
		V_{DD} = 5V		0.05		0	0.05		0.05	V
		V_{DD} = 10V		0.05		0	0.05		0.05	V
		V_{DD} = 15V		0.05		0	0.05		0.05	V
V_{OH}	High Level Output Voltage	$\|I_O\| < 1\mu A$								
		V_{DD} = 5V	4.95		4.95	5		4.95		V
		V_{DD} = 10V	9.95		9.95	10		9.95		V
		V_{DD} = 15V	14.95		14.95	15		14.95		V
V_{IL}	Low Level Input Voltage	V_{DD} = 5V, V_O = 0.5V or 4.5V		1.5			1.5		1.5	V
		V_{DD} = 10V, V_O = 1V or 9V		3.0			3.0		3.0	V
		V_{DD} = 15V, V_O = 1.5V or 13.5V		4.0			4.0		4.0	V
V_{IH}	High Level Input Voltage	V_{DD} = 5V, V_O = 0.5V or 4.5V	3.5		3.5			3.5		V
		V_{DD} = 10V, V_O = 1V or 9V	7.0		7.0			7.0		V
		V_{DD} = 15V, V_O = 1.5V or 13.5V	11.0		11.0			11.0		V
I_{OL}	Low Level Output Current	V_{DD} = 5V, V_O = 0.4V	0.64		0.51	0.88		0.36		mA
		V_{DD} = 10V V_O = 0.5V	1.6		1.3	2.25		0.9		mA
		V_{DD} = 15V, V_O = 1.5V	4.2		3.4	8.8		2.4		mA
I_{OH}	High Level Output Current	V_{DD} = 5V, V_O = 4.6V	−0.64		−0.51	−0.88		−0.36		mA
		V_{DD} = 10V, V_O = 9.5V	−1.6		−1.3	−2.25		−0.9		mA
		V_{DD} = 15V, V_O = 13.5V	−4.2		−3.4	−8.8		−2.4		mA
I_{IN}	Input Current	V_{DD} = 15V, V_{IN} = 0V		−0.1		-10^{-5}	−0.1		−1.0	μA
		V_{DD} = 15V, V_{IN} = 15V		0.1		10^{-5}	0.1		1.0	μA

DC Electrical Characteristics CD4029BC (Note 2)

PARAMETER		CONDITIONS	−40°C		25°C			85°C		UNITS
			MIN	MAX	MIN	TYP	MAX	MIN	MAX	
I_{DD}	Quiescent Device Current	V_{DD} = 5V		20			20		150	μA
		V_{DD} = 10V		40			40		300	μA
		V_{DD} = 15V		80			80		600	μA
V_{OL}	Low Level Output Voltage	$\|I_O\| < 1\mu A$								
		V_{DD} = 5V		0.05		0	0.05		0.05	V
		V_{DD} = 10V		0.05		0	0.05		0.05	V
		V_{DD} = 15V		0.05		0	0.05		0.05	V
V_{OH}	High Level Output Voltage	$\|I_O\| < 1\mu A$								
		V_{DD} = 5V	4.95		4.95	5		4.95		V
		V_{DD} = 10V	9.95		9.95	10		9.95		V
		V_{DD} = 15V	14.95		14.95	15		14.95		V

DC Electrical Characteristics (Cont'd.) CD4029BC (Note 2)

PARAMETER		CONDITIONS	−40°C		25°C			85°C		UNITS
			MIN	MAX	MIN	TYP	MAX	MIN	MAX	
V_{IL}	Low Level Input Voltage	V_{DD} = 5V, V_O = 0.5 or 4.5V		1.5			1.5		1.5	V
		V_{DD} = 10V, V_O = 1V or 9V		3.0			3.0		3.0	V
		V_{DD} = 15V, V_O = 1.5V or 13.5V		4.0			4.0		4.0	V
V_{IH}	High Level Input Voltage	V_{DD} = 5V, V_O = 0.5V or 4.5V	3.5		3.5			3.5		V
		V_{DD} = 10V, V_O = 1V or 9V	7.0		7.0			7.0		V
		V_{DD} = 15V, V_O = 1.5V or 13.5V	11.0		11.0			11.0		V
I_{OL}	Low Level Output Current	V_{DD} = 5V, V_O = 0.4V	0.52		0.44	0.88		0.36		mA
		V_{DD} = 10V, V_O = 0.5V	1.3		1.1	2.25		0.9		mA
		V_{DD} = 15V, V_O = 1.5V	3.6		3.0	8.8		2.4		mA
I_{OH}	High Level Output Current	V_{DD} = 5V, V_O = 4.6V	−0.52		−0.44	−0.88		−0.36		mA
		V_{DD} = 10V, V_O = 9.5V	−1.3		−1.1	−2.25		−0.9		mA
		V_{DD} = 15V, V_O = 13.5V	−3.6		−3.0	−8.8		−2.4		mA
I_{IN}	Input Current	V_{DD} = 15V, V_{IN} = 0V		−0.3		-10^{-5}	−0.3		−1.0	μA
		V_{DD} = 15V, V_{IN} = 15V		0.3		10^{-5}	0.3		1.0	μA

AC Electrical Characteristics T_A = 25°C, C_L = 50 pF, R_L = 200 k, Input $t_{rCL} = t_{fCL}$ = 20 ns, unless otherwise specified

PARAMETER		CONDITIONS	MIN	TYP	MAX	UNITS
CLOCKED OPERATION						
t_{PHL} or t_{PLH}	Propagation Delay Time to Q Outputs	V_{DD} = 5V		200	400	ns
		V_{DD} = 10V		85	170	ns
		V_{DD} = 15V		70	140	ns
t_{PHL} or t_{PLH}	Propagation Delay Time to Carry Output	V_{DD} = 5V		320	640	ns
		V_{DD} = 10V		135	270	ns
		V_{DD} = 15V		110	220	ns
t_{PHL} or t_{PLH}	Propagation Delay Time to Carry Output	V_{DD} = 5V, C_L = 15 pF		285	570	ns
		V_{DD} = 10V, C_L = 15 pF		120	240	ns
		V_{DD} = 15V, C_L = 15 pF		95	190	ns
t_{THL} or t_{TLH}	Transition Time/Q or Carry Output	V_{DD} = 5V		100	200	ns
		V_{DD} = 10V		50	100	ns
		V_{DD} = 15V		40	80	ns
t_{WH} or t_{WL}	Minimum Clock Pulse Width	V_{DD} = 5V		160	320	ns
		V_{DD} = 10V		70	135	ns
		V_{DD} = 15V		55	110	ns
t_{rCL} or t_{fCL}	Maximum Clock Rise and Fall Time	V_{DD} = 5V	15			μs
		V_{DD} = 10V	10			μs
		V_{DD} = 15V	5			μs
t_{SU}	Minimum Set-Up Time	V_{DD} = 5V		180	360	ns
		V_{DD} = 10V		70	140	ns
		V_{DD} = 15V		55	110	ns
f_{CL}	Maximum Clock Frequency	V_{DD} = 5V	1.5	3.1		MHz
		V_{DD} = 10V	3.7	7.4		MHz
		V_{DD} = 15V	4.5	9		MHz
C_{IN}	Average Input Capacitance	Any Input		5	7.5	pF
C_{PD}	Power Dissipation Capacitance	Per Package, (Note 3)		65		pF
PRESET ENABLE OPERATION						
t_{PHL} or t_{PLH}	Propagation Delay Time to Q Output	V_{DD} = 5V		285	570	ns
		V_{DD} = 10V		115	230	ns
		V_{DD} = 15V		95	195	ns

AC Electrical Characteristics (Cont'd.) $T_A = 25°C$, $C_L = 50$ pF, $t_{rCL} = t_{fCL} = 20$ ns, unless otherwise specified

PARAMETER		CONDITIONS	MIN	TYP	MAX	UNITS
PRESET ENABLE OPERATION (con't)						
t_{PHL} or t_{PLH}	Propagation Delay Time to Carry Output	$V_{DD} = 5V$		400	800	ns
		$V_{DD} = 10V$		165	330	ns
		$V_{DD} = 15V$		135	260	ns
t_{WH}	Minimum Preset Enable Pulse Width	$V_{DD} = 5V$		80	160	ns
		$V_{DD} = 10V$		30	60	ns
		$V_{DD} = 15V$		25	50	ns
t_{REM}	Minimum Preset Enable Removal Time	$V_{DD} = 5V$		150	300	ns
		$V_{DD} = 10V$		60	120	ns
		$V_{DD} = 15V$		50	100	ns
CARRY INPUT OPERATION						
t_{PHL} or t_{PLH}	Propagation Delay Time to Carry Output	$V_{DD} = 5V$		265	530	ns
		$V_{DD} = 10V$		110	220	ns
		$V_{DD} = 15V$		90	180	ns
t_{PHL}, t_{PLH}	Propagation Delay Time to Carry Output	$V_{DD} = 5V$, $C_L = 15$ pF		200	400	ns
		$V_{DD} = 10V$, $C_L = 15$ pF		85	170	ns
		$V_{DD} = 15V$, $C_L = 15$ pF		70	140	ns

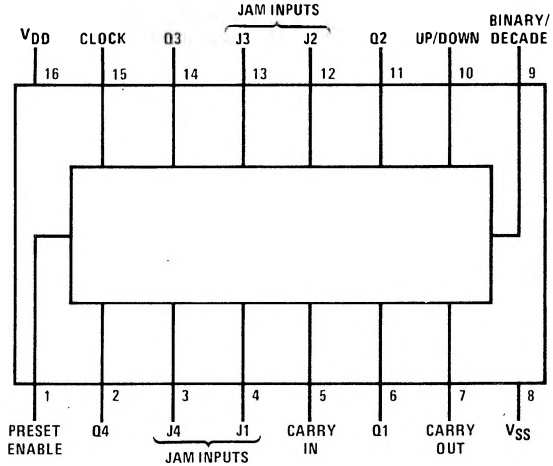
Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Note 2: $V_{SS} = 0V$ unless otherwise specified.

Note 3: C_{PD} determines the no load ac power consumption of any CMOS device. For complete explanation, see 54C/74C Family Characteristics application note, AN-90.

Connection Diagram

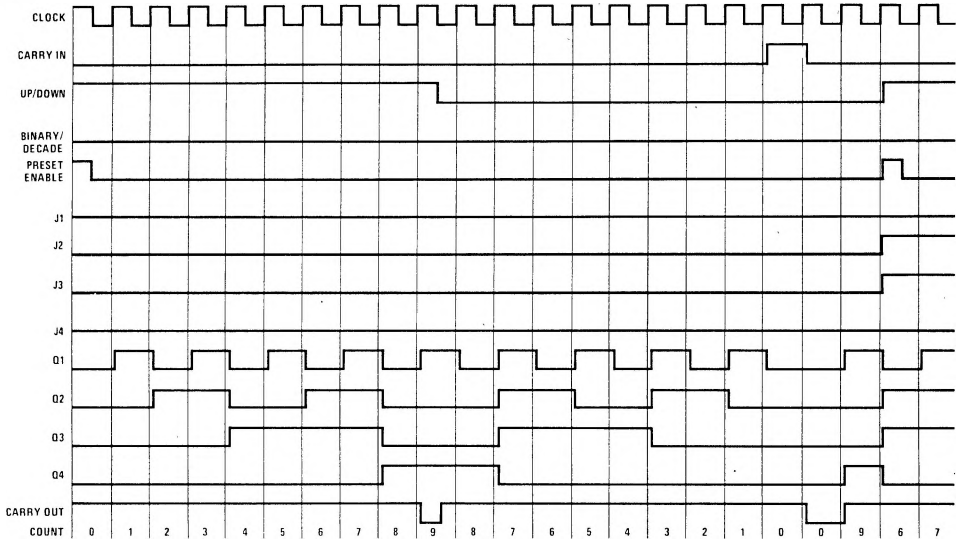
Dual-In-Line Package



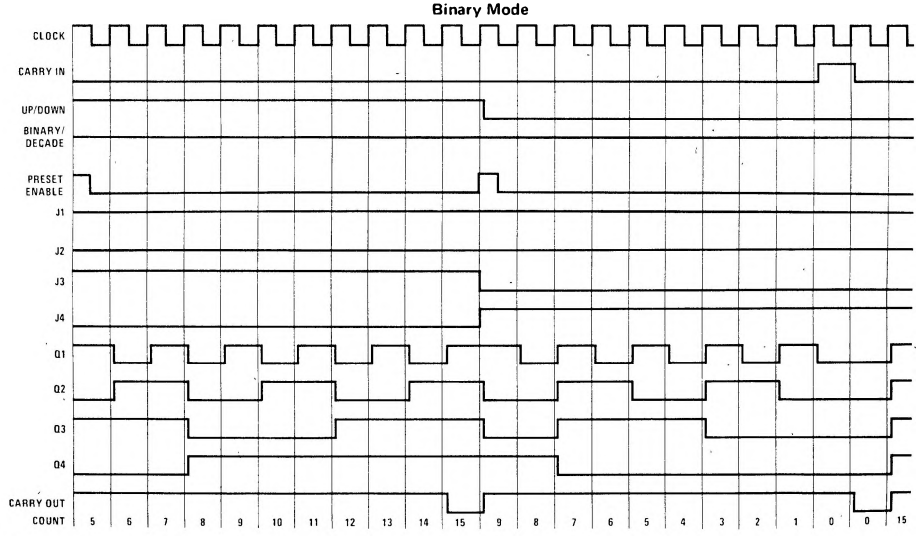
TOP VIEW

Logic Waveforms

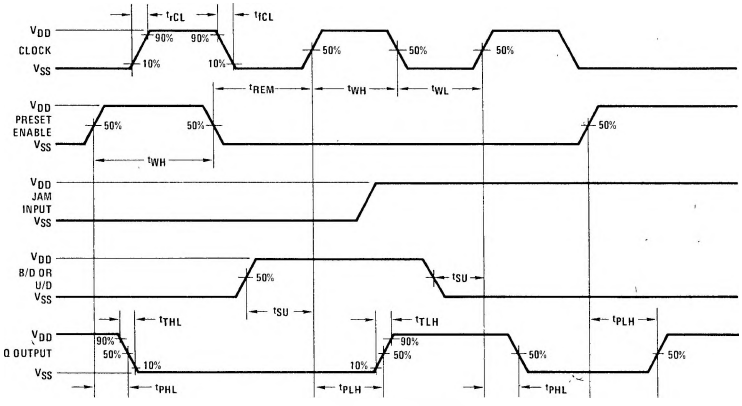
Decade Mode



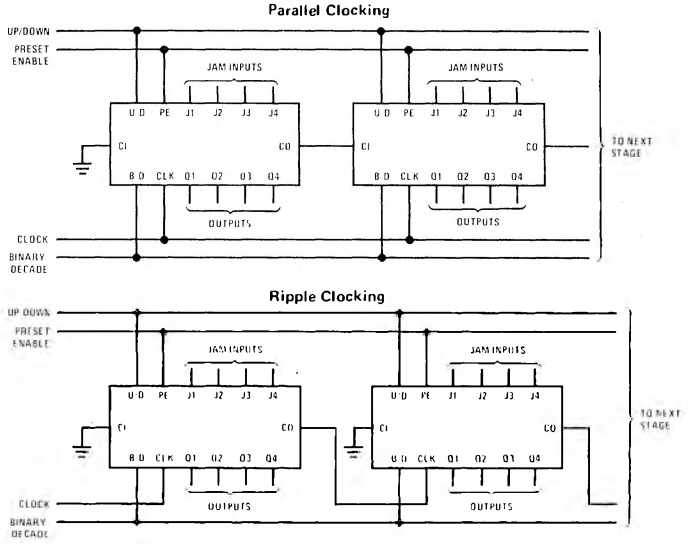
Binary Mode



Switching Time Waveforms



Cascading Packages



Carry out lines at the 2nd or later stages may have a negative-going spike due to differential internal delays. These spikes do not affect counter operation, but if the carry out is used to trigger external circuitry the carry out should be gated with the clock.